



Product Summary

BV _{DSS}	RDS(ON) Max	I _D T _A = +25°C
30V	58mΩ @ V _{GS} = 8V	4.6A
	62mΩ @ VGs = 4.5V	4.4A

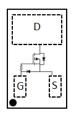
Description

This new generation MOSFET is designed to minimize the footprint in handheld and mobile application. It can be used to replace many small signals MOSFET with as really small footprint.

Applications

- Battery Management
- Load Switch
- Battery Protection
- Handheld and Mobile Application

X4-DSN1006-3 (Type C)



Top View

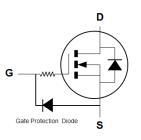
N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low Qg & Qgd
- Small Footprint
- Low Profile 0.20mm Height
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: X4-DSN1006-3
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 (2)
- Weight: 0.00029 grams (Approximate)



Equivalent Circuit

Ordering Information (Note 4)

e Packaging
3 (Type C) 10000/Tape & Reel
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1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



T = Product Type Marking Code

YW = Date Code Marking

Y or \overline{Y} = Year (ex: 0 = 2020)

W or \overline{W} = Week (ex: a =Week 27; z Represents Week 52 and 53)

Date Code Kev

Notes:

Dale Coue Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
Week 1-26				27-52					53			
Code	A-Z				a	I-Z				Z		



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	30	V		
Gate-Source Voltage	Vgss	12	V		
Continuous Drain Current (Note 5) VGS = 8V	Steady State	T _A = +25°C T _A = +70°C	٦D	4.6 3.7	A
Continuous Drain Current (Note 5) $V_{GS} = 4.5V$	ID	4.4 3.5	A		
Pulsed Drain Current (Note 6)	Ідм	20	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	1.12	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	Reja	113.4	°C/W
Power Dissipation (Note 5)	PD	1.88	W
Thermal Resistance, Junction to Ambient $@T_A = +25$ °C (Note 5)	Reja	66.4	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

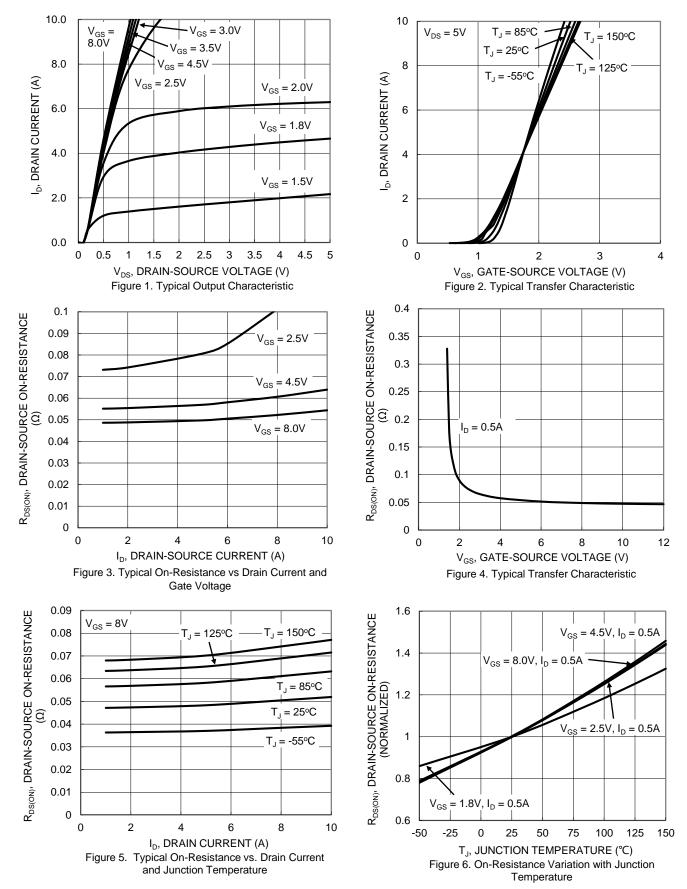
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						-	
Drain-Source Breakdown Voltage	BVDSS	30	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	100	nA	V _{DS} = 24V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_		50	nA	$V_{GS} = 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			•	•	•	·	
Gate Threshold Voltage	Vgs(th)	0.65	0.85	1.1	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		_	47	58		VGS = 8V, ID = 0.5A	
Static Drain-Source On-Resistance		_	54	62	mΩ	VGS = 4.5V, ID = 0.5A	
Static Drain-Source On-Resistance	RDS(ON)	_	71	110	11122	Vgs = 2.5V, ID = 0.5A	
		_	104	160		VGS = 1.8V, ID = 0.5A	
Diode Forward Voltage	Vsd	_	0.7	0.9	V	VGS = 0V, IS = 0.5A	
Reverse Recovery Charge	Q _{RR}	_	2.4	_	nC	V _{DD} = 15V, I _F = 0.5A,	
Reverse Recovery Time	trr	_	7.1	_	ns	di/dt = 300A/µs	
DYNAMIC CHARACTERISTICS (Note 9)	l						
Input Capacitance	Ciss	_	126	—			
Output Capacitance	Coss	_	81	—	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	4.5	—			
Series Gate Resistance	Rg	_	3.7	_	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$	
Total Gate Charge	Qg	_	1.4	_			
Gate-Source Charge	Q _{gs}	_	0.2	_		Vgs = 4.5V, Vds = 15V,	
Gate-Drain Charge	Q _{gd}	_	0.2	_	nC	I _D = 0.5A	
Gate Charge at VTH	Qg(TH)	_	0.2	_			
Turn-On Delay Time	t _{D(ON)}	_	4.3	—			
Turn-On Rise Time	tR	_	1.9	—	1	V _{DS} = 15V, V _{GS} = 4.5V,	
Turn-Off Delay Time	tD(OFF)	_	9.1	—	ns	$R_g = 2\Omega$, $I_D = 0.5A$	
Turn-Off Fall Time	tF	_	5.1	_	1		

Notes:

Device mounted on FR-4 material with 1inch² (6.45cm²), 2-oz. (0.071mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

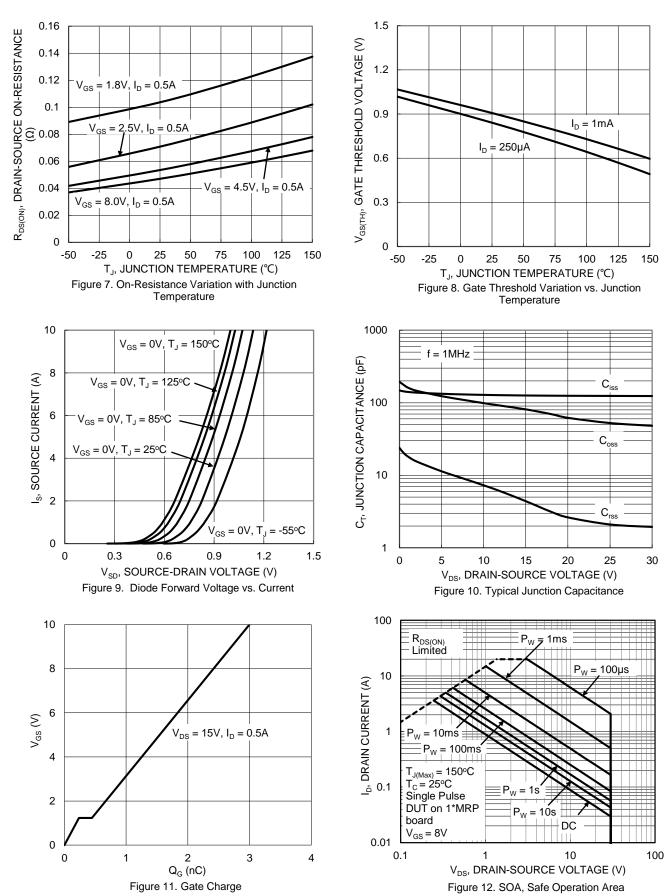


DMN3061LCA3



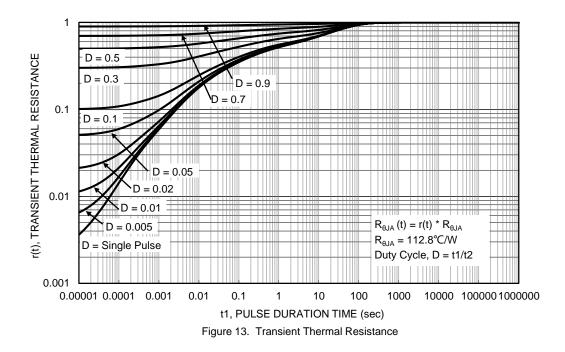
DMN3061LCA3 Document number: DS42490 Rev. 2 - 2







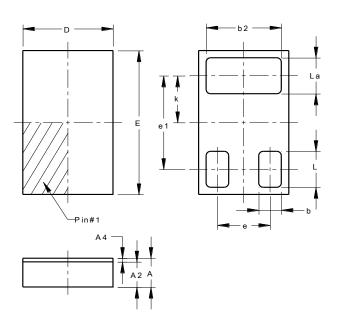






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

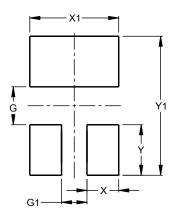


X4-DSN1006-3								
(Type C)								
Dim	Min	Тур						
Α	0.18	0.22	0.20					
A2			0.175					
A4			0.025					
b	0.14	0.16	0.15					
b2	0.49	0.51	0.50					
D	0.56	0.64	0.60					
E	0.96	1.04	1.00					
е			0.35					
e1			0.65					
k			0.325					
L	0.24	0.26	0.25					
La	0.24	0.26	0.25					
All	Dimensi	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
G	0.40
G1	0.20
Х	0.15
X1	0.50
Y	0.25
Y1	0.90



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